

isc N-Channel MOSFET Transistor

IXFH102N15T

• FEATURES

- Static drain-source on-resistance:
 R_{DS}(on) ≤ 18mΩ@V_{GS}=10V
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATION

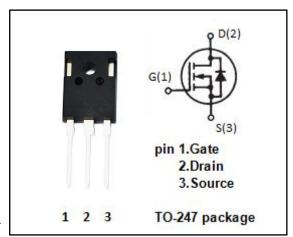
- DC/DC Converters
- · High Speed Power Switching Applications

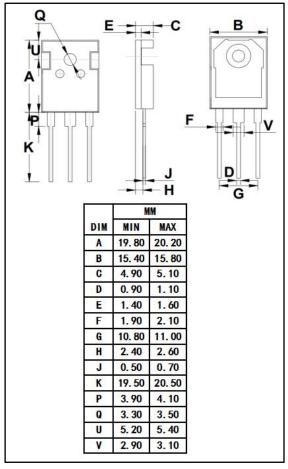
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	150	V
V_{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	102	Α
I _{DM}	Drain Current-Single Pulsed	300	Α
P _D	Total Dissipation @Tc=25℃ 30		W
Tj	Operating Junction Temperature -55~175		$^{\circ}$
T _{stg}	Storage Temperature	-55~175	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(j-c)}	Junction-to-case thermal resistance	0.5	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V; ID = 250 μ A	150		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; ID = 1mA	2.5	5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 51A		18	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V		±200	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V		5	- μΑ
		V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J = 150°C		750	
V _{SD}	Diode forward voltage	I _F = 100A; V _{GS} = 0V		1.3	V



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